



CAN Bus Driver and Receiver

DESCRIPTION

The Si9200EY is designed to interface between the Intel 82526 CAN controller and the physical bus to provide drive capability to the bus and differential receive capability to the controller. It is designed to absorb typical electrical transients on the bus which may occur in an automotive or industrial application, and protect itself against any abnormal bus conditions. The transmitter will be disabled during these conditions and will be re-enabled when the abnormal condition is cleared.

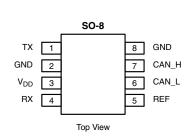
The Si9200EY is built using the Siliconix BiC/DMOS process. This process supports CMOS, DMOS, and isolated bipolar transistors and uses an epitaxial layer to prevent latchup. The bus line pins are diode protected and can be driven beyond the V_{DD} to ground range.

The Si9200EY is offered in the space efficient 8-pin highdensity surface-mount plastic package and is specified over the automotive temperature range (- 40 °C to 125 °C). The Si9200EY is available in lead free.

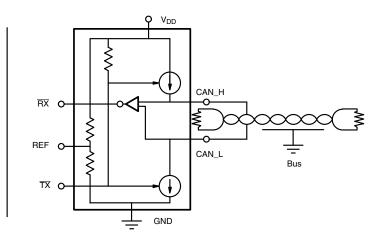
FEATURES

- Survives Ground Shorts and Transients on Multiplexed Bus in Automotive and Industrial Applications
- Single Power Supply
- Compatible with Intel 82526 CAN Controller
- Direct Interface No External Components Required
- Automotive Temperature Range (- 40 °C to 125 °C)

PIN CONFIGURATION AND FUNCTIONAL BLOCK DIAGRAM



Si9200FY-T1 Ordering Information: Si9200EY-T1-E3 (Lead Free)



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ABSOLUTE MAXIMUM RATINGS ^a					
Parameter	Limit	Unit			
Operating Temperature (T _A)	- 40 to 125	°C			
Junction and Storage Temperature	- 55 to 150	1 0			
Voltage On Any Pin (except CAN_H and CAN_L) with Respect to Ground	- 0.3 to V _{DD} + 0.3				
Voltage On CAN_H and CAN_L with Respect to Ground	- 3 to 16	V			
Supply Voltage, V _{DD}	- 0.3 to 12				
Continuous Output Current	± 100	mA			
Thermal Ratings ^b : R _{thJA}	62.5 (no airflow)	°C			

Notes:

b. Mounted on 1-IN², FR4 PC Board.

RECOMMENDED OPERATING RANGE					
Parameter	Limit	Unit			
V_{DD}	4.75 to 5.25	V			
Bus Load Resistance	60	Ω			

SPECIFICATIONS							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V _{DD} = 4.75 V to 5.25 V		T _A	Limits = - 40 V to 12	25 °C	
	,			Min.b	Typ. ^c	Max.b	Unit
Input							
TX Input Voltage High	V _{INH}			4			v
TX Input Voltage Low	V _{INL}					1] '
TX Input Current Low	I _{IL}	$\overline{TX} = 0 V$		- 50		- 2	μΑ
TX Input Current High	I _{IH}	$\overline{TX} = V_{DD}$		- 1		1	μΑ
Output							
	V _{CAN_HR} , V _{CAN_LR}			2	2.5	3	
Bus Recessive	V _{DIF} =	$\overline{TX} = V_{INH}, R_L =$	- 0.5	0	0.05		
	V _{CAN_HR} - V _{CAN_LR}			0.0		0.00	
	V _{CAN_HD}		2.75	3.5	4.5		
Bus Dominant	V _{CAN_LD}	$\overline{TX} = V_{INL}, R_L = 6$	0.5	1.5	2.25		
	$V_{DIF} = V_{CAN_HD} - V_{CAN_LD}$	INE.		1.5	2	3	
Reference Output	V_{REF}	- 25 μA ≤ I _{REF} ≤ 2	5 μΑ	0.5 V _{DD} - 0.2	0.5 V _{DD}	0.5 V _{DD} + 0.2	٧
Receive Output	V _{RXH}		I _{OUT} = - 10 μA	V _{DD} - 0.3	V _{DD} - 0.05		
(Bus Recessive			I _{OUT} = - 100 μA	V _{DD} - 1	V _{DD} - 0.2		
Conditions)		0.5 (Bus Recessive)	I _{OUT} = - 2 mA	V _{DD} - 1.75	V _{DD} - 1		
		$\overline{TX} = V_{INH}$	I _{OUT} = 10 μA		0.05	0.3	
Receive Output (Bus Dominant		- 0.8 ≤ V _{CAN_H} ≤ 7 - 2 ≤ V _{CAN_L} ≤ 5.8	I _{OUT} = 100 μA		0.2	1	
Conditions)	TIXE	0.9 ≤ V _{CAN_H} - V _{CAN_L} ≤ 5 (Bus Dominant)	I _{OUT} = 2 mA		1	1.75	
	R _{IN} , BUS_L			5		50	
Internal Resistance from Bus Pins	R _{IN} , BUS_H			5		50	kΩ
	R _{DIFF}	TX = V _{INH} (Recessive)		10		100	
Internal Capacitance from Bus Pins ^c	C _{IN} (CAN_H, CAN_L)					50	pF

a. Extended exposure to the absolute maximum ratings or stresses beyond these ratings may affect device reliability or may cause permanent damage to the device. Functional operation at conditions other than the recommended operating conditions is not implied.





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SPECIFICATION	NS S					
Parameter	Symbol	Test Conditions Unless Otherwise Specified V _{DD} = 4.75 V to 5.25 V	Limits T _A =- 40 V to 125 °C			
	,		Min.b	Typ. ^c	Max.b	Unit
Dynamic		•				
<u>Propagation Delay</u> - TX to V _{DIFF} High	t _{ON-TX}				50	
Propagation Delay - TX to V _{DIFF} Low	t _{OFF-TX}				50	ns
Propagation Delay - TX to Receive Low	t _{ON-RX}				120	113
Propagation Delay - TX to Receive High	t _{OFF-RX}				120	
Supply						
Cumpaly Current	L	$\overline{\text{TX}} = \text{V}_{\text{INH}}, \text{V}_{\text{DD}} = 5.25 \text{ V}, \text{R}_{\text{L}} = 60 \Omega \text{ (Recessive)}$			25	m 1
Suppply Current	I _{DD}	$\overline{TX} = V_{INL}, V_{DD} = 5.25 \text{ V}, R_L = 60 \Omega \text{ (Dominant)}$	40		75	mA
Transient ^c						
Electrostatic Discharge Human Body Model	V _{ESD}	C_L = 100 pF, R_L = 1500 Ω MIL-STD-883D, Method 3015		2000		V
Bus Transient Voltage	V _{TRANS}	R_S = 1000 Ω, 1 ms	- 60		60	
Protection				•	•	
Thermal Trip Point ^c	T _{TRP}		150	165	180	°C
Thermal Hysteresis ^c	T _{HYS}		10	20	30	7

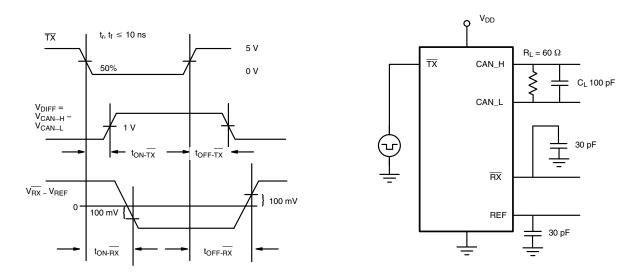
Notes:

- a. Typical values are for DESIGN AID ONLY at T_A = 25 °C, not guaranteed nor subject to production testing.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.
- c. Guaranteed by design, not subject to production test.

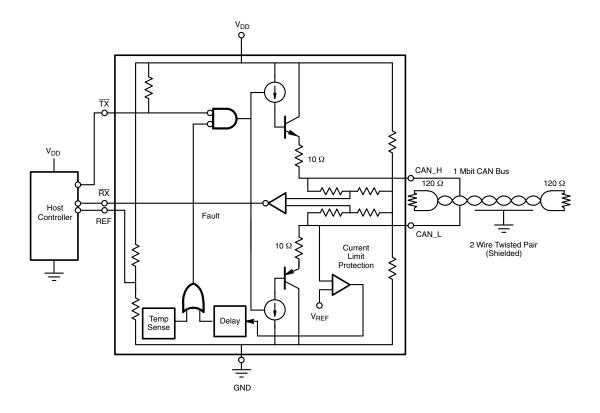
Truth Table						
TX	Mode	Bus State	CAN_H	CAN_L	RX	
Low	Transmit	Dominant	High	Low	Low	
High (or Floating)	Transmit and Receive	Recessive	Floating	Floating	High	
High (or Floating)	Receive	Recessive	High	Low	Low	

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SWITCHING TIME TEST CIRCUIT

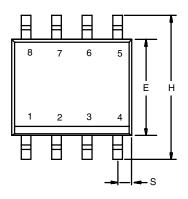


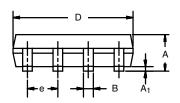
CIRCUIT SCHEMATIC

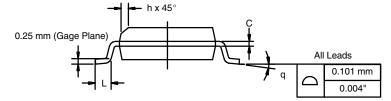




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
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